



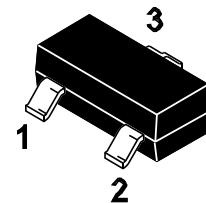
# PJM84PSA

## P-Channel Enhancement Mode Power MOSFET

### Features

- Energy efficient
- Low threshold voltage
- High-speed switching
- ESD protected(HBM) up to 2KV
- Miniature surface mount package saves board space
- $V_{DS} = -50V$ ,  $I_D = -0.13A$   
 $R_{DS(on)} < 8\Omega$  @  $V_{GS} = -10V$

SOT-23



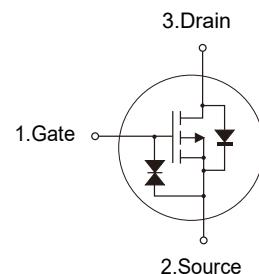
1. Gate 2. Source 3. Drain

Marking Code:P84

### Applications

- PWM applications
- Load switch
- Power management

Schematic Diagram



### Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$-V_{DS}$	50	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current-Continuous	$-I_D$	0.13	A
Drain Current-Pulsed <sup>Note1</sup> at $t_p < 10\mu s$	$-I_{DM}$	0.52	A
Maximum Power Dissipation	$P_D$	225	mW
Junction Temperature	$T_J$	150	°C
Storage Temperature Range	$T_{STG}$	-55 to +150	°C

### Thermal Characteristics

Thermal Resistance, Junction-to-Ambient <sup>Note2</sup>	$R_{\theta JA}$	556	°C/W
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### Electrical Characteristics

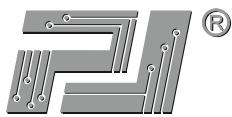
(Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	-V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	50	--	--	V
Zero Gate Voltage Drain Current	-I <sub>DSS</sub>	V <sub>DS</sub> =-50V, V <sub>GS</sub> =0V	--	--	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±10	μA
Gate Threshold Voltage <sup>Note3</sup>	-V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	0.9	1.6	2	V
Drain-Source On-Resistance <sup>Note3</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-0.1A	--	2.5	8	Ω
		V <sub>GS</sub> =-5V, I <sub>D</sub> =-0.1A	--	3	10	Ω
Forward Transconductance <sup>Note3</sup>	g <sub>FS</sub>	V <sub>DS</sub> =-25V, I <sub>D</sub> =-0.1A	0.05	--	--	S
<b>Dynamic Characteristics</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V, f=1MHz	--	43	--	pF
Output Capacitance	C <sub>oss</sub>		--	2.9	--	pF
Reverse Transfer Capacitance	C <sub>rss</sub>		--	1.8	--	pF
<b>Switching Characteristics</b>						
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =-30V, V <sub>GS</sub> =-4.5V I <sub>D</sub> =-0.15A, R <sub>GEN</sub> =2.5Ω	--	8.6	--	nS
Turn-on Rise Time	t <sub>r</sub>		--	20	--	nS
Turn-off Delay Time	t <sub>d(off)</sub>		--	15	--	nS
Turn-off Fall Time	t <sub>f</sub>		--	77	--	nS
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =-30V, I <sub>D</sub> =0.15A V <sub>GS</sub> =-10V	--	1.77	--	nC
Gate-Source Charge	Q <sub>gs</sub>		--	0.57	--	nC
Gate-Drain Charge	Q <sub>gd</sub>		--	0.18	--	nC
<b>Source-Drain Diode Characteristics</b>						
Diode Forward Voltage <sup>Note3</sup>	-V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =-0.13A	--	--	1.2	V
Diode Forward Current <sup>Note2</sup>	-I <sub>S</sub>		--	--	0.13	A

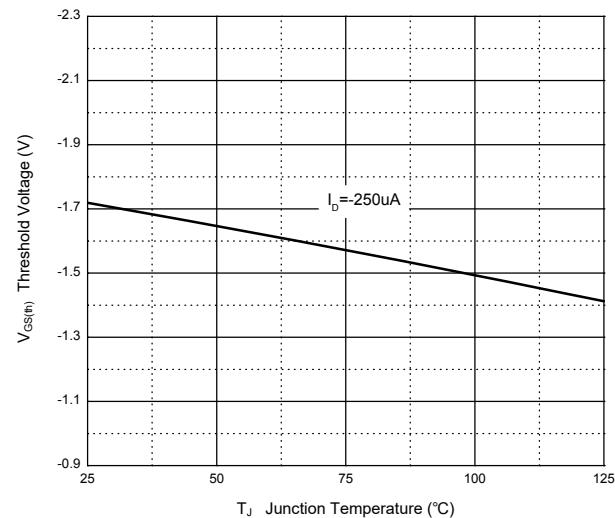
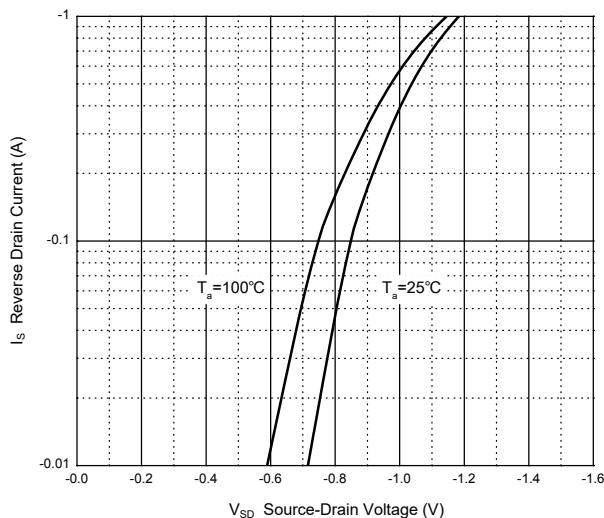
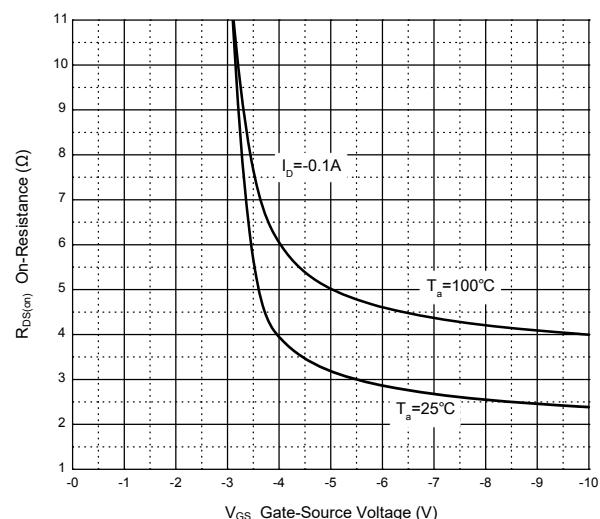
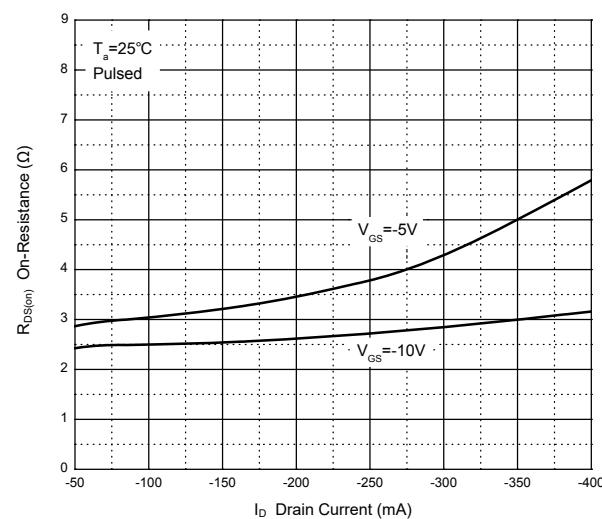
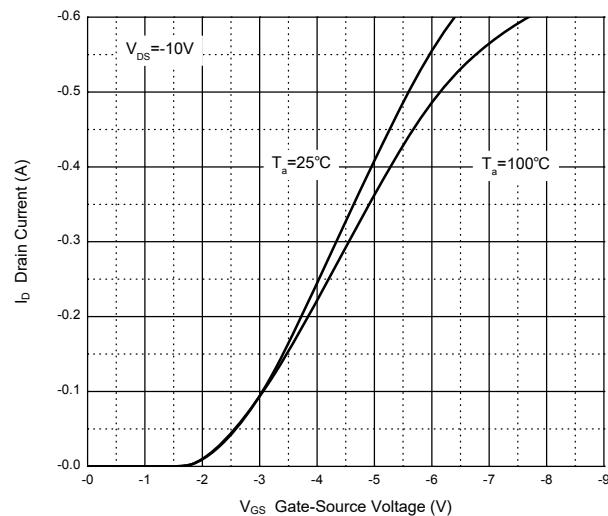
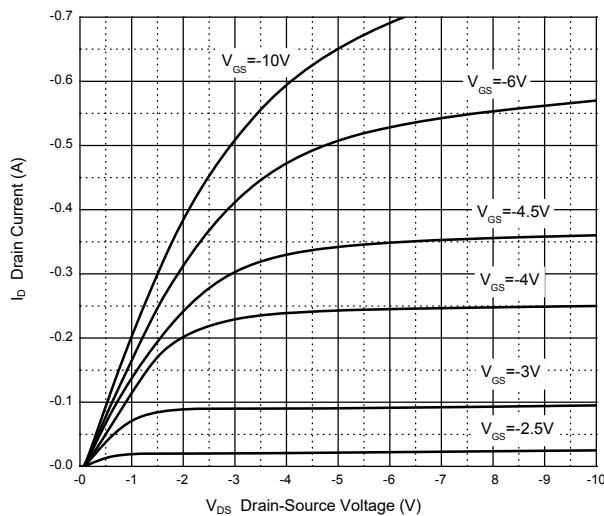
Note: 1. Repetitive rating : Pulse width limited by junction temperature.

2. Surface Mounted on FR4 Board, t ≤ 10 sec.

3. Pulse Test: Pulse width≤300μs, duty cycle≤2%.



### Typical Characteristic Curves





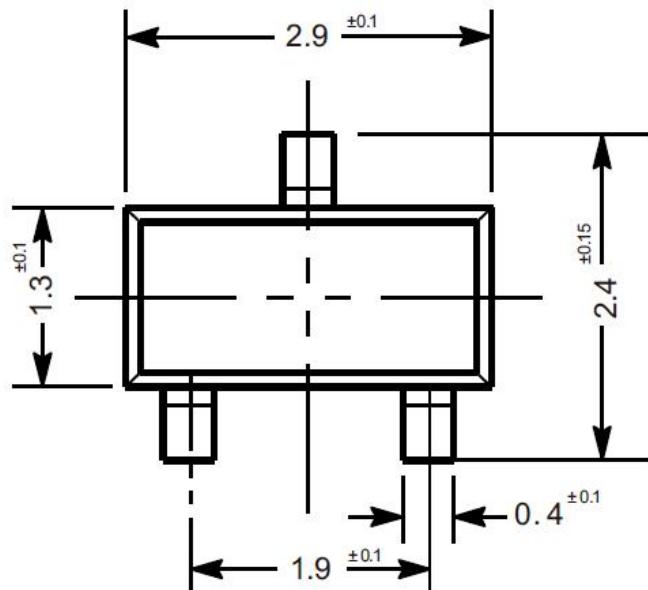
# PJM84PSA

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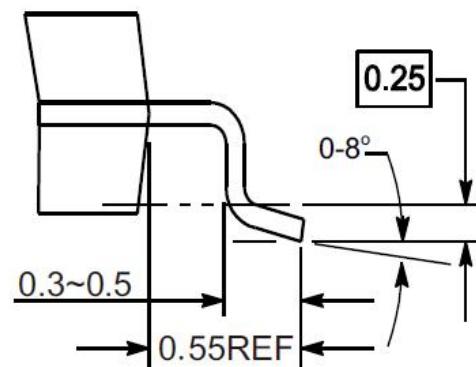
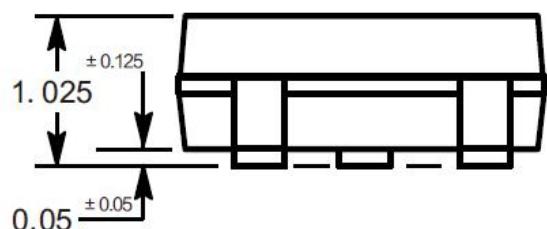
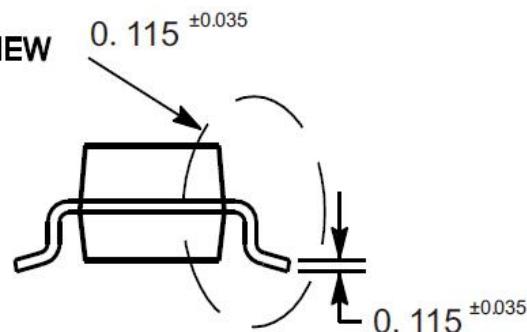
### Package Outline

SOT-23

Dimensions in mm



SEE VIEW



VIEW C

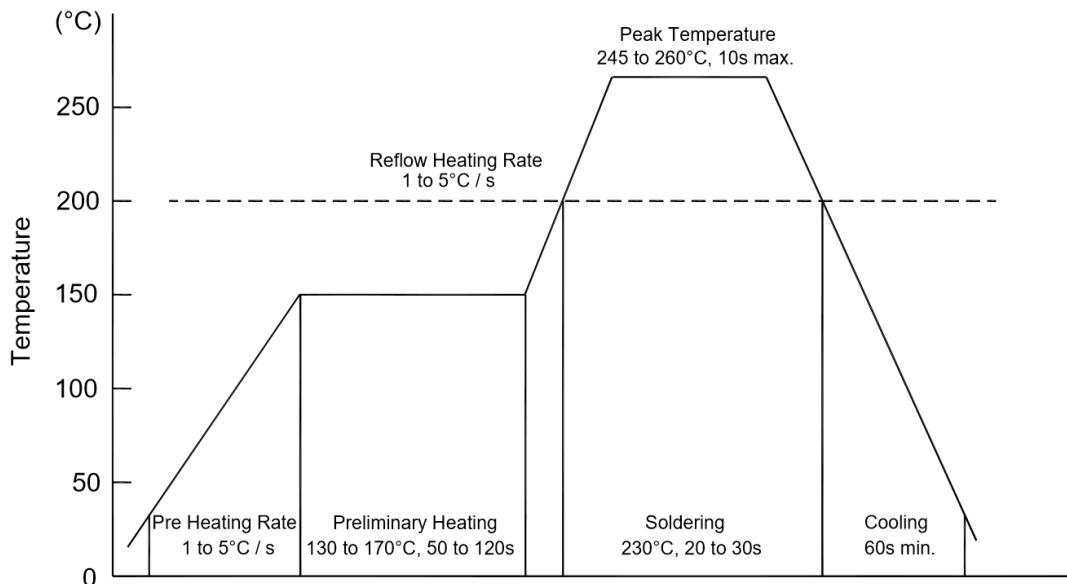
### Ordering Information

Device	Package	Shipping
PJM84PSA	SOT-23	3,000PCS/Reel&7inches



## Conditions of Soldering and Storage

### ◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

### ◆ Conditions of hand soldering

- Temperature: 370 °C
- Time: 3s max.
- Times: one time

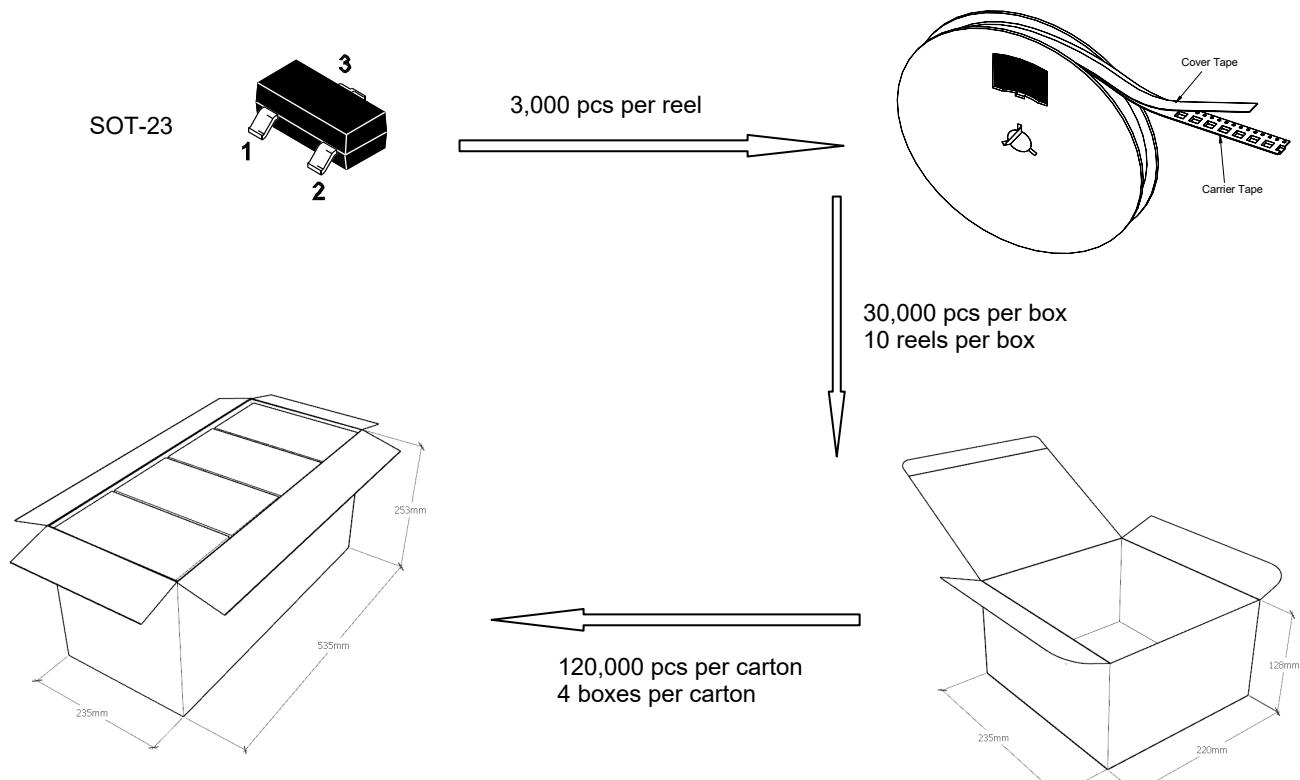
### ◆ Storage conditions

- **Temperature**  
5 to 40 °C
- **Humidity**  
30 to 80% RH
- **Recommended period**  
One year after manufacturing

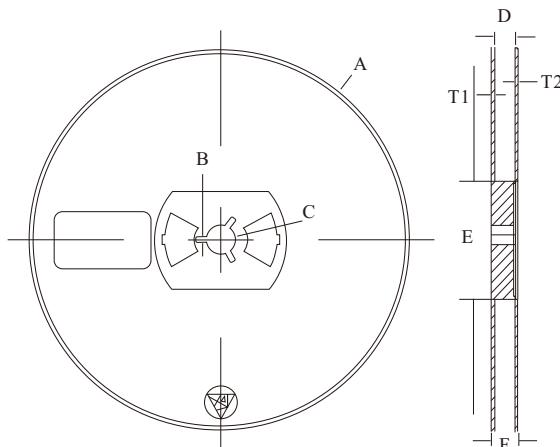


## Package Specifications

- The method of packaging



### ◆ Embossed tape and reel data



Symbol	Value (unit: mm)
A	$\varnothing 177.8 \pm 1$
B	$2.7 \pm 0.2$
C	$\varnothing 13.5 \pm 0.2$
E	$\varnothing 54.5 \pm 0.2$
F	$12.3 \pm 0.3$
D	$9.6 +2/-0.3$
T1	$1.0 \pm 0.2$
T2	$1.2 \pm 0.2$

Reel (7")

